<u>TOSHIBA</u>

TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR SILICON N CHANNEL IGBT

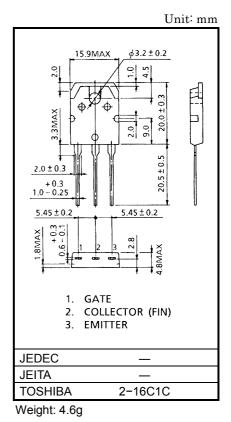
GT20J301

HIGH POWER SWITCHING APPLICATIONS MOTOR CONTROL APPLICATIONS

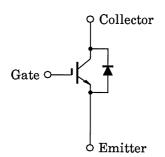
- The 3rd Generation
- Enhancement-Mode
- High Speed : $t_f = 0.30 \mu s$ (Max.)
- Low Saturation Voltage : V_{CE} (sat) = 2.7V (Max.)
- FRD included between Emitter and Collector

MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | | SYMBOL | RATING | UNIT | |
|--|-----|------------------|---------|------|--|
| Collector-Emitter Voltage | | V _{CES} | 600 | V | |
| Gate-Emitter Voltage | | V _{GES} | ±20 | V | |
| Collector Current | DC | Ι _C | 20 | А | |
| | 1ms | I _{CP} | 40 | А | |
| Emitter-Collector Forward Current | DC | ١ _F | 20 | А | |
| | 1ms | I _{FM} | 40 | А | |
| Collector Power Dissipation (Tc = 25°C) | | PC | 130 | W | |
| Junction Temperature | | Tj | 150 | °C | |
| Storage Temperature Range | | T _{stg} | -55~150 | °C | |



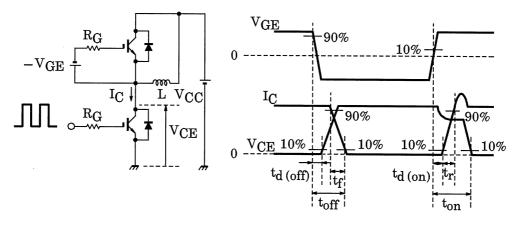
EQUIVALENT CIRCUIT



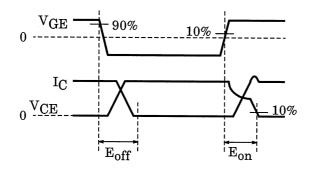
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | | SYMBOL | TEST CONDITION | MIN | TYP. | MAX | UNIT |
|--------------------------------------|---------------|-----------------------|---|-----|------|------|------|
| Gate Leakage Current | | I _{GES} | $V_{GE} = \pm 20V, V_{CE} = 0$ | - | — | ±500 | nA |
| Collector Cut-Off Current | | ICES | V _{CE} = 600V, V _{GE} = 0 | | _ | 1.0 | mA |
| Gate-Emitter Cut-Off Voltage | | V _{GE (OFF)} | I _C = 2mA, V _{CE} = 5V | 5.0 | _ | 8.0 | V |
| Collector-Emitter Saturation Voltage | | V _{CE (sat)} | I _C = 20A, V _{GE} = 15V | | 2.1 | 2.7 | V |
| Input Capacitance | | C _{ies} | V _{CE} = 20V, V _{GE} = 0, f = 1MHz | | 1450 | _ | pF |
| Switching Time | Rise Time | tr | Inductive Load V_{CC} = 300V, I _C = 20A V_{GG} = ±15V, R _G = 56 Ω (Note) | _ | 0.12 | _ | - µs |
| | Turn-On Time | t _{on} | | _ | 0.40 | _ | |
| | Fall Time | t _f | | _ | 0.15 | 0.30 | |
| | Turn-Off Time | t _{off} | | | 0.70 | _ | |
| Peak Forward Voltage | | VF | I _F = 20A, V _{GE} = 0 | | _ | 2.0 | V |
| Reverse Recovery Time | | t _{rr} | I _F = 20A, di / dt = −100A / μs | | _ | 200 | ns |
| Thermal Resistance (IGBT) Rtl | | R _{th (j−c)} | _ | _ | _ | 0.96 | °C/W |
| Thermal Resistance (Diode) | | R _{th (j−c)} | _ | _ | _ | 2.5 | °C/W |

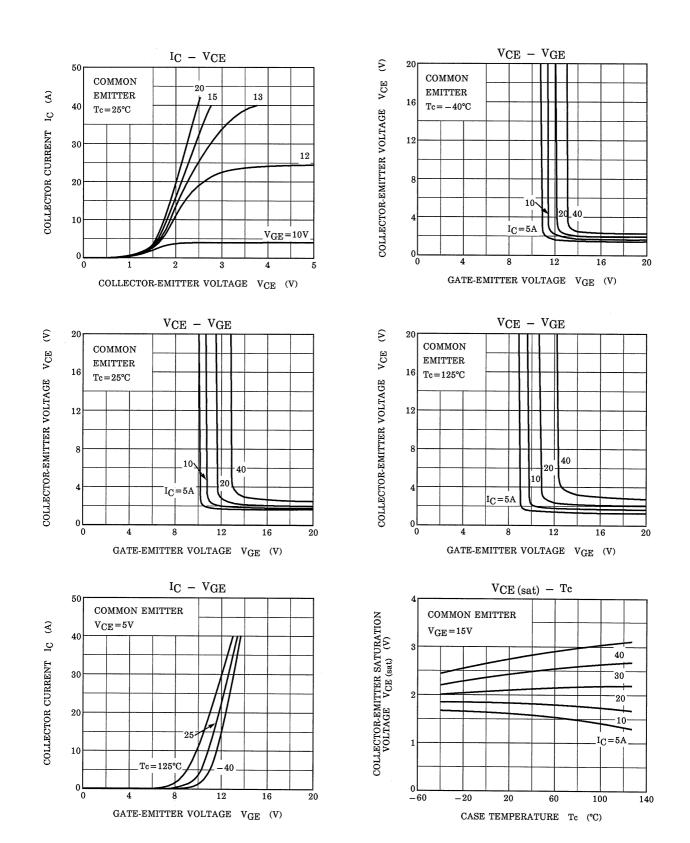
Note : Switching time measurement circuit and input / output waveforms



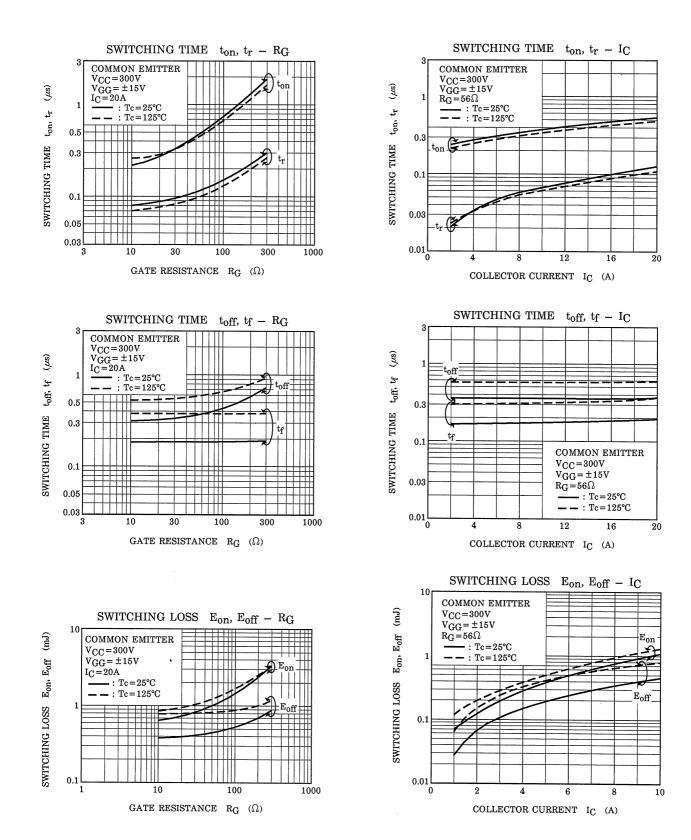
Switching loss measurement waveforms



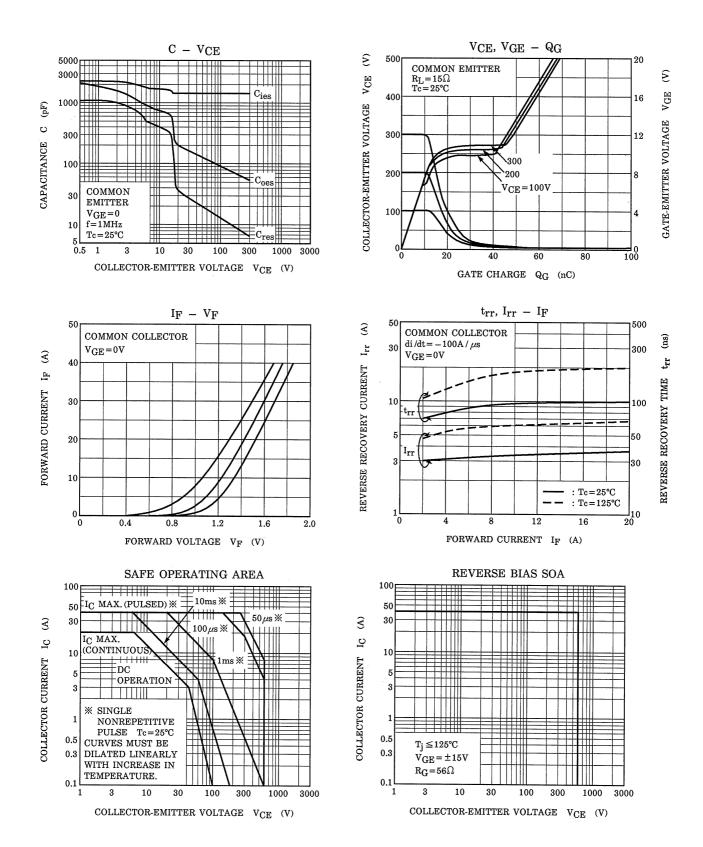
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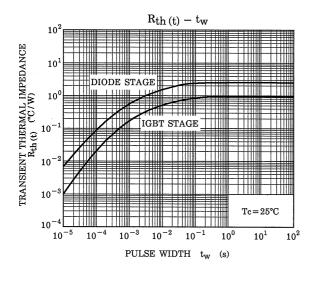


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